RT3N33M-T150

Composite Transistor With Resistor
For Switching Application
Silicon Epitaxial Type

AEC-Q101 Compliance

DESCRIPTION

RT3N33M is composite transistor built with two RT1N441 chips in SC-88 package.

FEATURE

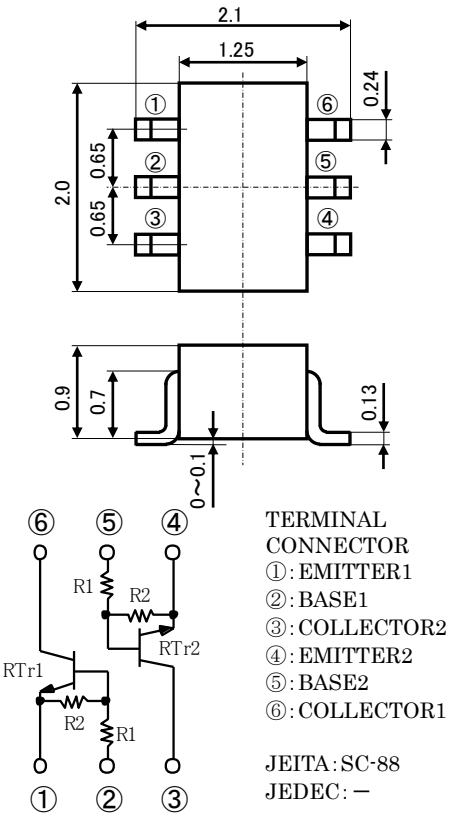
Silicon epitaxial type
Each transistor elements are independent.
Mini package for easy mounting

APPLICATION

Inverted circuit, Switching circuit,
Interface circuit, Driver circuit

OUTLINE DRAWING

Unit:mm



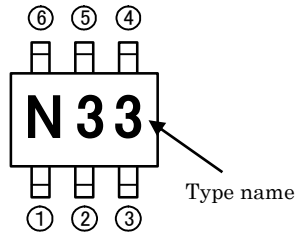
TERMINAL CONNECTOR
①:EMITTER1
②:BASE1
③:COLLECTOR2
④:EMITTER2
⑤:BASE2
⑥:COLLECTOR1

JEITA:SC-88
JEDEC:－

MAXIMUM RATING(Ta=25℃)(RTr1, RTr2 COMMON)

SYMBOL	PARAMETER	RATING	UNIT
V_{CBO}	Collector to Base voltage	50	V
V_{EBO}	Emitter to Base voltage	10	V
V_{CEO}	Collector to Emitter voltage	50	V
V_{IN}	Input voltage	40	V
I_C	Collector current	100	mA
I_{CM}	Peak Collector current	200	mA
P_T	Total dissipation	200	mW
T_j	Junction temperature	+150	℃
T_{stg}	Storage temperature	-55～+150	℃

MARKING



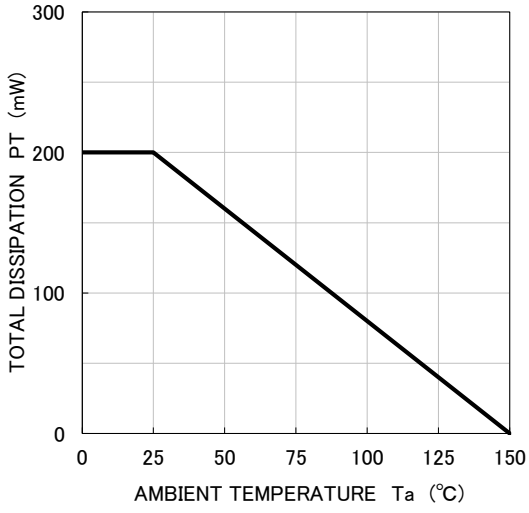
ELECTRICAL CHARACTERISTICS(Ta=25℃)(RTr1, RTr2 COMMON)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
$V_{(BR)CEO}$	Collector to Emitter break down voltage	I_C=100μA, R_{BE}=∞	50	－	－	V
I_{CBO}	Collector cut off current	V_{CB}=50V, I_E=0	－	－	0.1	μA
I_{EBO}	Emitter cut off current	V_{EB}=5V, I_C=0	41	53	76	μA
h_{FE}	DC forward current gain	V_{CE}=5V, I_C=5mA	50	－	－	－
$V_{CE(sat)}$	Collector to Emitter saturation voltage	I_C=10mA, I_B=0.5mA	－	－	0.3	V
$V_{I(ON)}$	Input on voltage	V_{CE}=0.2V, I_C=5mA	－	2.2	5.0	V
$V_{I(OFF)}$	Input off voltage	V_{CE}=5V, I_C=100μA	0.8	1.1	－	V
R_1	Input resistor	－	33	47	61	kΩ
R_2/R_1	Resistor ratio	－	0.9	1.0	1.1	－
f_T	Gain band width product	V_{CE}=6V, I_E=-10mA	－	200	－	MHz

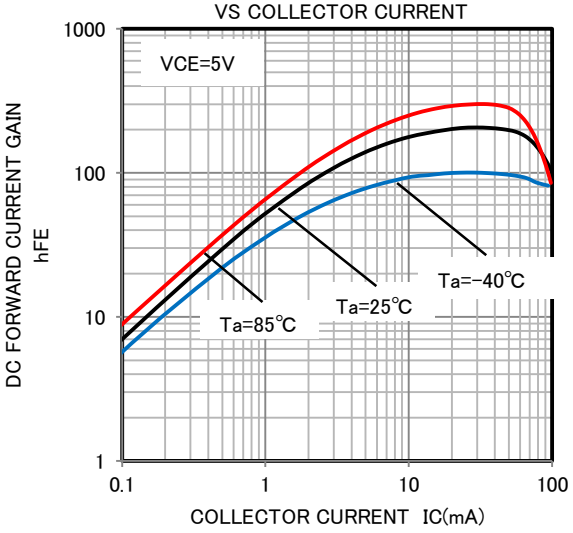
TYPICAL CHARACTERISTICS

(RTr1,RTr2 COMMON)

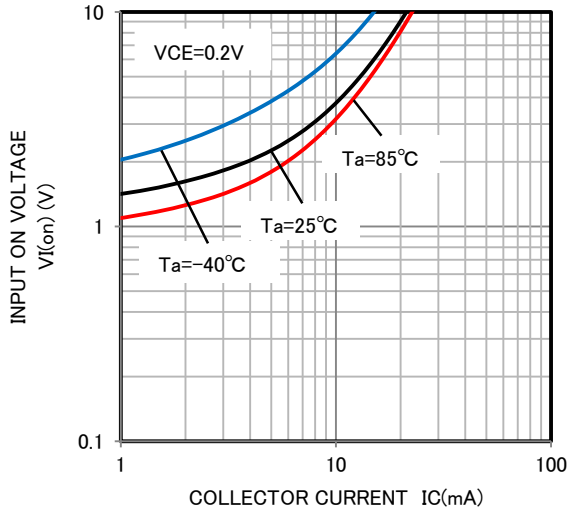
TOTAL DISSIPATION
VS AMBIENT TEMPERATURE



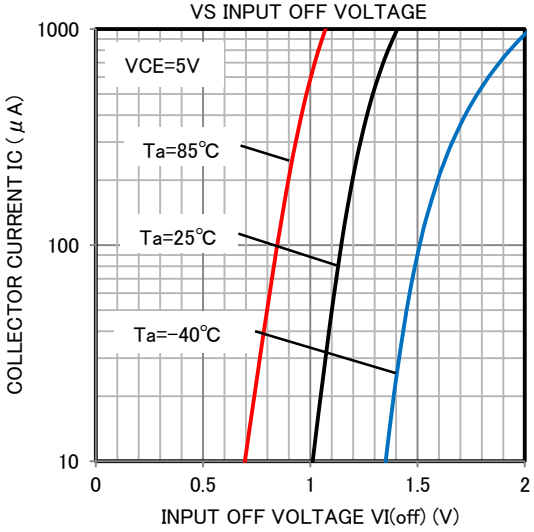
DC FORWARD CURRENT GAIN
VS COLLECTOR CURRENT



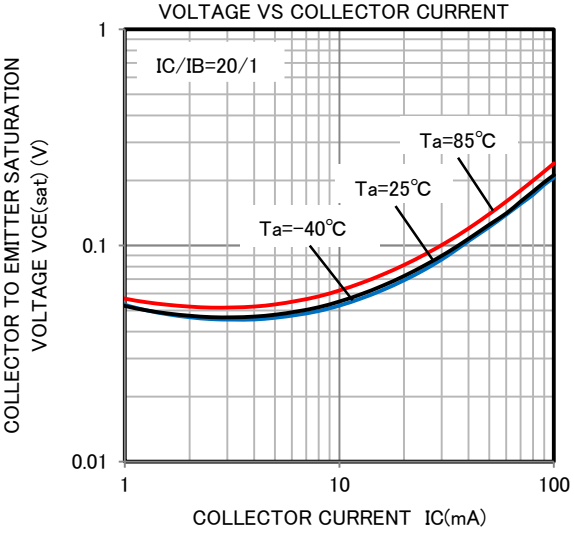
INPUT ON VOLTAGE
VS COLLECTOR CURRENT



COLLECTOR CURRENT
VS INPUT OFF VOLTAGE



COLLECTOR TO EMITTER SATURATION
VOLTAGE VS COLLECTOR CURRENT



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